

Numerical Simulations of an Inductive Type Fault Current Limiter Based on Electromagnetic and Temperature Dependent Parameters

Pedro Arsénio<sup>1</sup>, João Murta-Pina<sup>1</sup>, Anabela Pronto<sup>1</sup>, Alfredo Álvarez<sup>2</sup>

<sup>1</sup> UNINOVA - CTS, Portugal

<sup>2</sup> Universidad de Extremadura, Spain

- 1. Introduction
- 2. Problem and Approaches
- 3. Results and Discussion
- 4. Conclusions

# • ° ° ° lntroduction

### **Motivation**

Inductive Type Limiters are commonly simulated in FEM software. For a proper accuracy, both electromagnetic and thermal phenomena must be taken into account.

The properties of high temperature superconducting (HTS) materials, such as electrical resistivity, heat capacity, thermal conductivity, critical current density and n-index, are strongly dependent on temperature values.

Objective

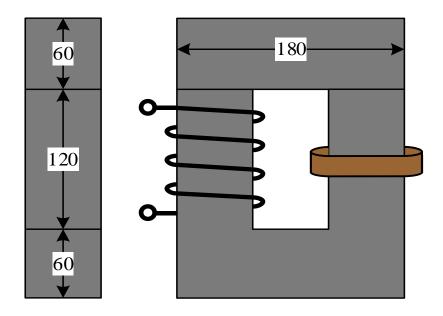
Develop a practical tool for a fast and accurate prediction of the behaviour of inductive type FCLs in electrical grids.

Reverse Engineering Simulations: Matlab/Simulink FEM Simulations: Matlab/Simulink + Cedrat Flux2D





### **Dimensions**



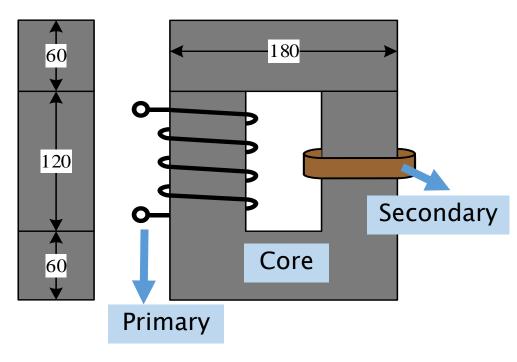


(Dimensions in mm)

Primary winding		
Material	Copper	
Number of turns	60	
Conductor cross section	1.5 mm <sup>2</sup>	
Inner radius	32.5 mm	
Width	0.7 mm	
Height	40 mm	
Secondary winding		
Material	Superpower SCS4050	
Number of turns	1	
Conductor cross section	0.4 mm <sup>2</sup>	
Critical current density at 77 K	250 A·mm <sup>-2</sup>	
Inner radius	40 mm	
Width	0.1 mm	
Height	4 mm	
Cryostat		
Material	Extruded polystyrene	
Inner radius	31.5 mm	
Outer radius	60.5 mm	
Wall thickness	6 mm	



### **Dimensions**

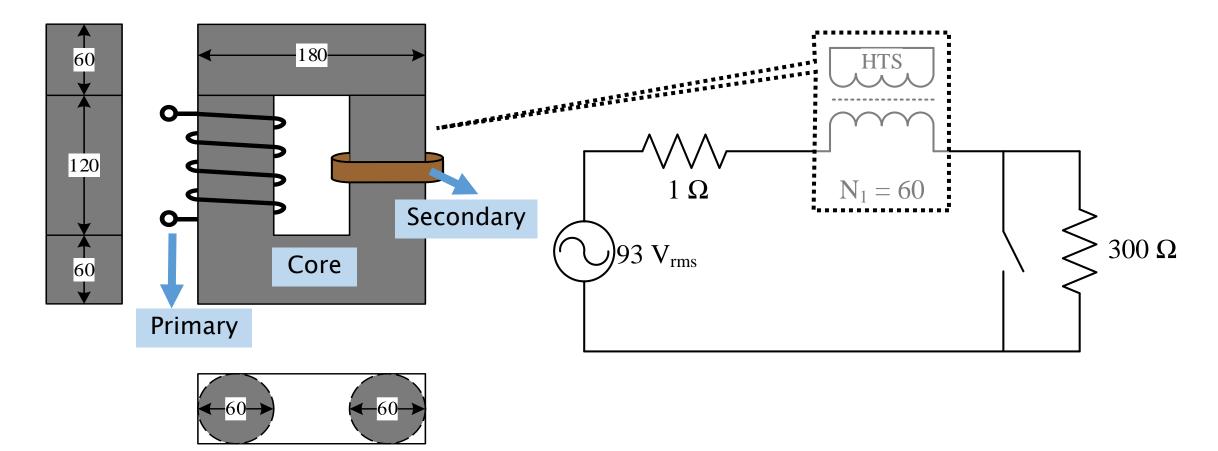


60	60

(Dimensions in mm)

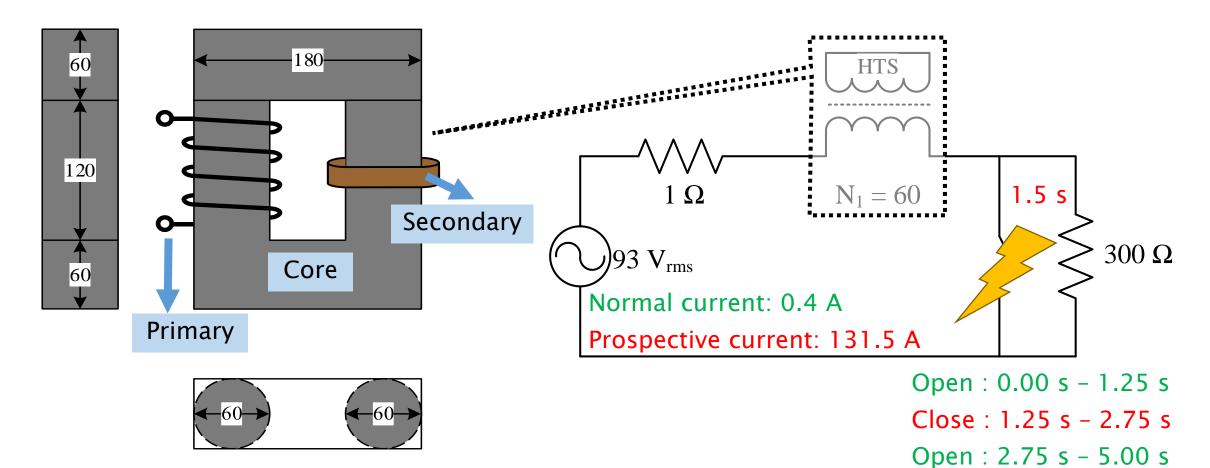
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### **Test Circuit**



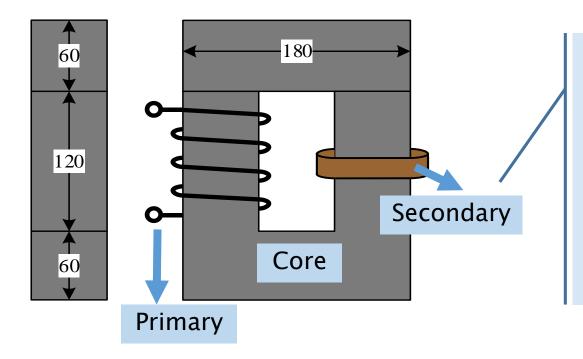
(Dimensions in mm)

### **Test Circuit**



(Dimensions in mm)

### **Parameters**



#### Temperature dependent properties:

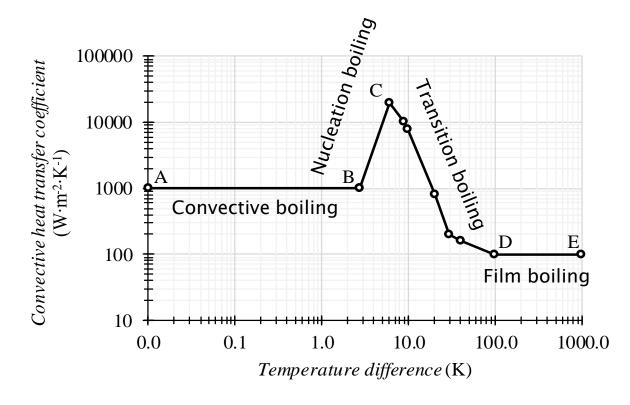
- Convective heat transfer.
- Critical current density.
- n-value.
- Resistivity of copper, silver, Hastelloy, (Re)BCO.
- Thermal conductivity.
- Heat capacity.



(Dimensions in mm)



### Parameters: Convective Heat Transfer Coefficient



$$h = \frac{Q_h}{\Lambda T} \qquad [W \cdot m^{-2} \cdot K^{-1}]$$

 $Q_h$ : Convective heat transfer (W·m<sup>-2</sup>)

 $\Delta T$ : Temperature difference (K)

#### Reference:

Kaufmann B, Dreier S, Haberstroh C and Grossmann S 2013 Integration of LN2 Multiphase Heat Transfer Into Thermal Networks for High Current Components *IEEE Trans. Appl.* Supercond. 23 5000104-5000104.



### Parameters: Critical Current Density and n-Value

$$J_C(T) = J_C(T_0) \cdot \left(\frac{1 - \left(\frac{T}{T_C}\right)^{\delta}}{1 - \left(\frac{T_0}{T_C}\right)^{\delta}}\right)^{\gamma} [A \cdot mm^{-2}]$$

$$T_C : Critical temperature (77.2 K)$$

$$\delta : Fitting parameter (-67.09)$$

$$\gamma : Fitting parameter (0.4107)$$

$$n(T) = n(T_0) \cdot \left(\frac{T_0}{T}\right)^{\kappa}$$

 $T_0$ : LN<sub>2</sub> temperature (77.2 K)

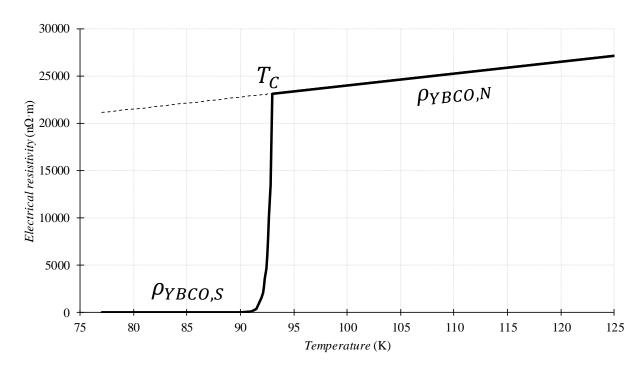
 $\gamma$ : Fitting parameter (0.4107)

 $\kappa$ : Fitting parameter (22.96)

- Lee W S, Nam S, Kim J, Lee J and Ko T K 2015 A Numerical and Experimental Analysis of the Temperature Dependence of the n-Index for 2G HTS Tape Surrounding the 77 K Temperature Range *IEEE Trans. Appl. Supercond.* **25** 1–4.
- Cedrat 2007 Flux 10 User's Guide vol 2.



### Parameters: Resistivity of Superconducting Layer



$$\begin{cases} \rho_{YBCO,S}(J,T) = \frac{E_c}{J} \cdot \left(\frac{J}{J_c(T)}\right)^{n(T)} \\ \rho_{YBCO,N}(T) = 1.25 \times 10^{-7} \cdot T + 1.15 \times 10^{-5} \\ \left[\Omega \cdot \mathsf{m}\right] \end{cases}$$

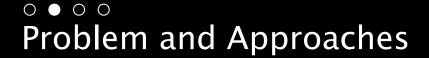
 $E_C$ : Critical electrical field (1  $\mu \cdot \text{cm}^{-1}$ )

J: Current density (K)

 $J_C$ : Critical current density (A·m<sup>-2</sup>)

*n* : n-value

T: Temperature (K)



## Parameters: Resistivity of Copper, Silver and Hastelloy Layers

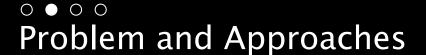
$$\rho_{Copper}(T) = 6.85 \times 10^{-11} \cdot T - 3.30 \times 10^{-9}$$

$$\rho_{Silver}(T) = 6.11 \times 10^{-11} \cdot T - 1.97 \times 10^{-9}$$

$$\rho_{Hastelloy}(T) = 1.17 \times 10^{-10} \cdot T + 1.25 \times 10^{-6}$$

 $[\Omega \cdot m]$ 

- Moore J P, McElroy D L and Graves R S 1967 Thermal Conductivity and Electrical Resistivity of High-Purity Copper from 78 to 400 K Can. J. Phys. 45 3849-65.
- Matula R A 1979 Electrical resistivity of copper, gold, palladium, and silver J. Phys. Chem. Ref. Data 8 1147.
- Lu J, Choi E S and Zhou H D 2008 Physical properties of Hastelloy® C-276TM at cryogenic temperatures J. Appl. Phys. 103 064908.



### Parameters: Thermal Conductivity

$$\lambda_{YBCO}(T) = 5$$

$$\lambda_{Copper}(T) = 416.3 - 5.904 \times 10^{-2} \cdot T + \frac{7.087 \times 10^7}{T^3}$$

$$\lambda_{Silver}(T) = 431.4 - 1.817 \times 10^{-2} \cdot T + \frac{1.708 \times 10^7}{T^3}$$

$$\lambda_{Hastelloy}(T) = 0.0238 \cdot T + 5.896$$

$$[W \cdot m^{-1} \cdot K^{-1}]$$

- Moore J P, McElroy D L and Graves R S 1967 Thermal Conductivity and Electrical Resistivity of High-Purity Copper from 78 to 400 K Can. J. Phys. 45 3849-65.
- Lu J, Choi E S and Zhou H D 2008 Physical properties of Hastelloy® C276 at cryogenic temperatures J. Appl. Phys. 103 064908.
- Ho C Y, Powell R W and Liley P E 1974 Journal of Physical and Chemical Reference Data, Volume 3.



### Parameters: Volumetric Heat Capacity

$$C_{YBCO}(T) = 4.05 \times 10^6 - 1.73 \times 10^8 \cdot T^{-0.9747}$$

$$C_{copper}(T) = -9.463 \times 10^7 \cdot T^{-0.8292} + 4.279 \times 10^6$$

$$C_{Silver}(T) = -1.983 \times 10^8 \cdot T^{-1.23} + 2.643 \times 10^6$$

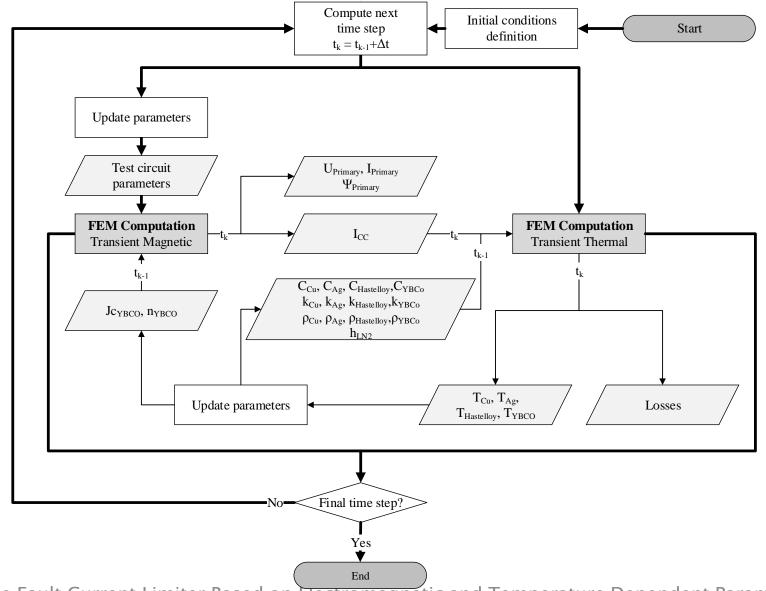
$$C_{Hastelloy}(T) = 4.14 \times 10^6 + \frac{5.92 \times 10^5 - 4.14 \times 10^6}{1 + \left(\frac{T}{120.42}\right)^{2.39}}$$

 $[J \cdot K^{-1}]$ 

- Lu J, Choi E S and Zhou H D 2008 Physical properties of Hastelloy® C-276TM at cryogenic temperatures J. Appl. Phys. 103 064908.
- Jensen J E, Tuttle W A, Stewart R B, Brechna H and Prodell A G 1980 Specific heat of some solids Brookhaven National Laboratory Selected Cryogenic Data Notebook, Volume 1.
- Smith D R and Fickett F R 1995 Low– Temperature Properties of Silver J. Res. Natl. Inst. Stand. Technol. 100 119.

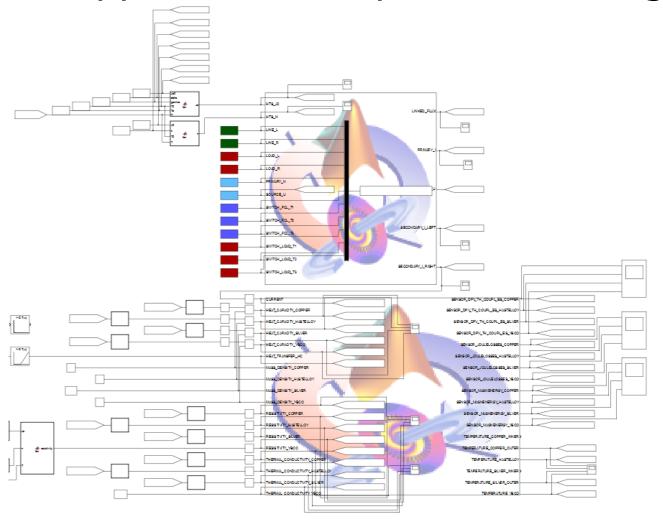
Approach 1: Coupled Electromagnetic-Thermal Simulation

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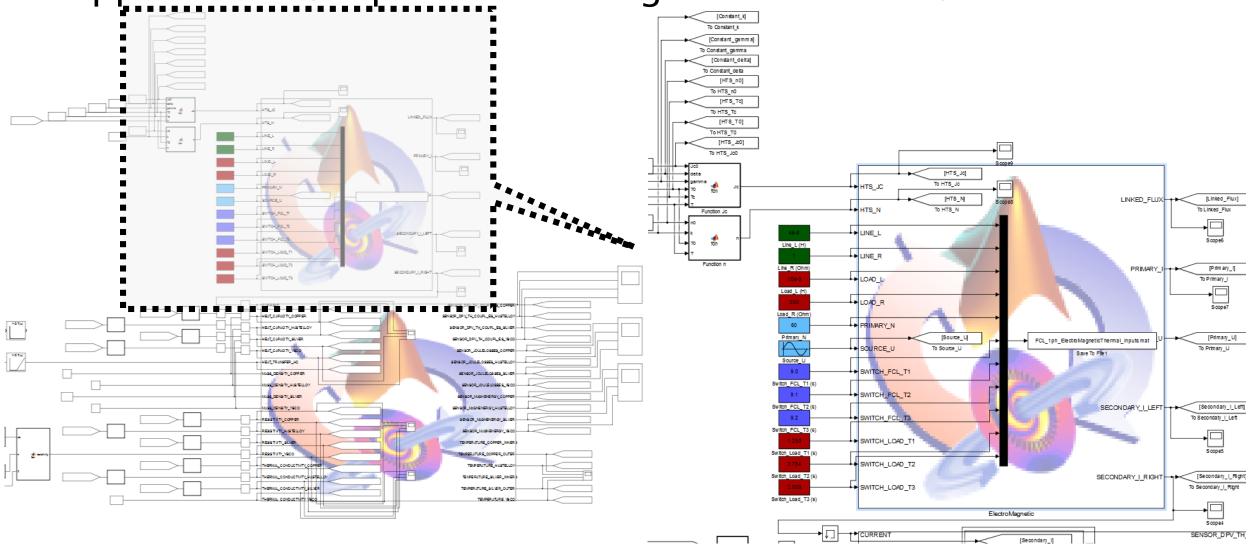
### Approach 1: Coupled Electromagnetic-Thermal Simulation



Co-Simulation: Matlab/Simulink + Cedrat Flux2D

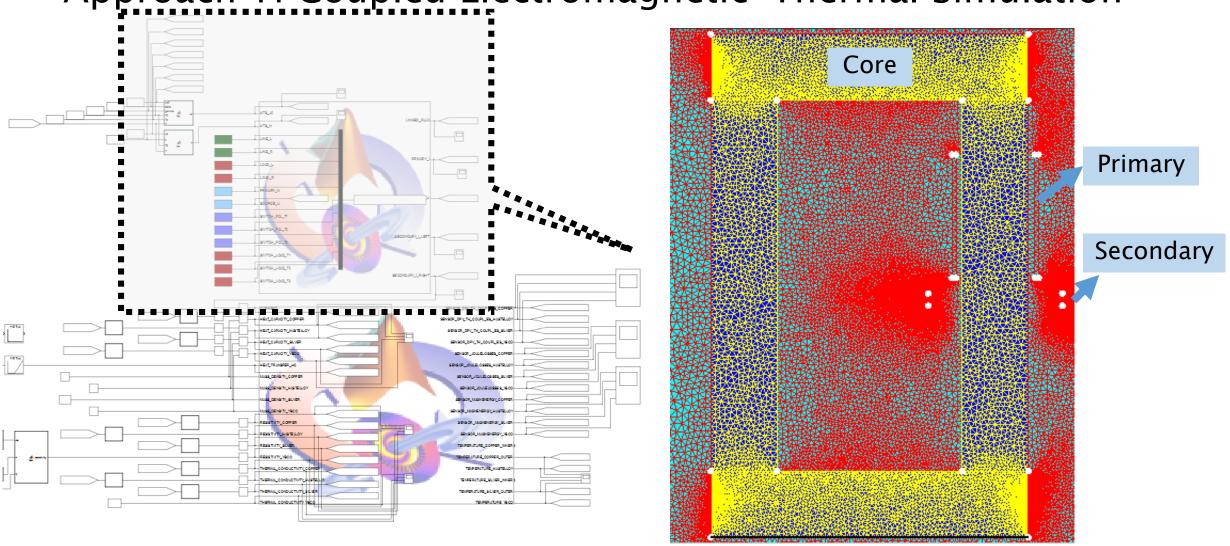
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Approach 1: Coupled Electromagnetic-Thermal Simulation



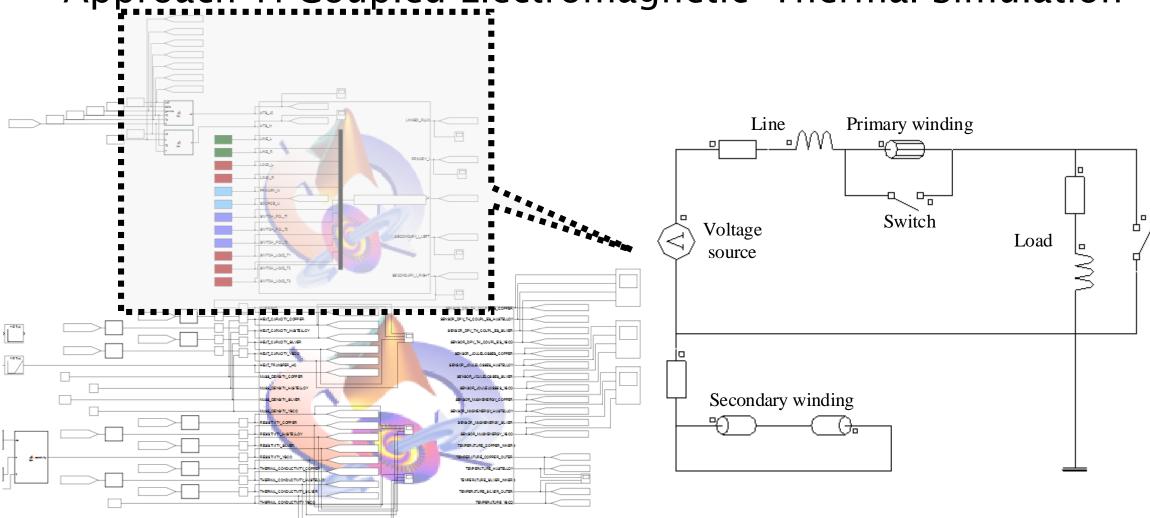
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### Approach 1: Coupled Electromagnetic-Thermal Simulation



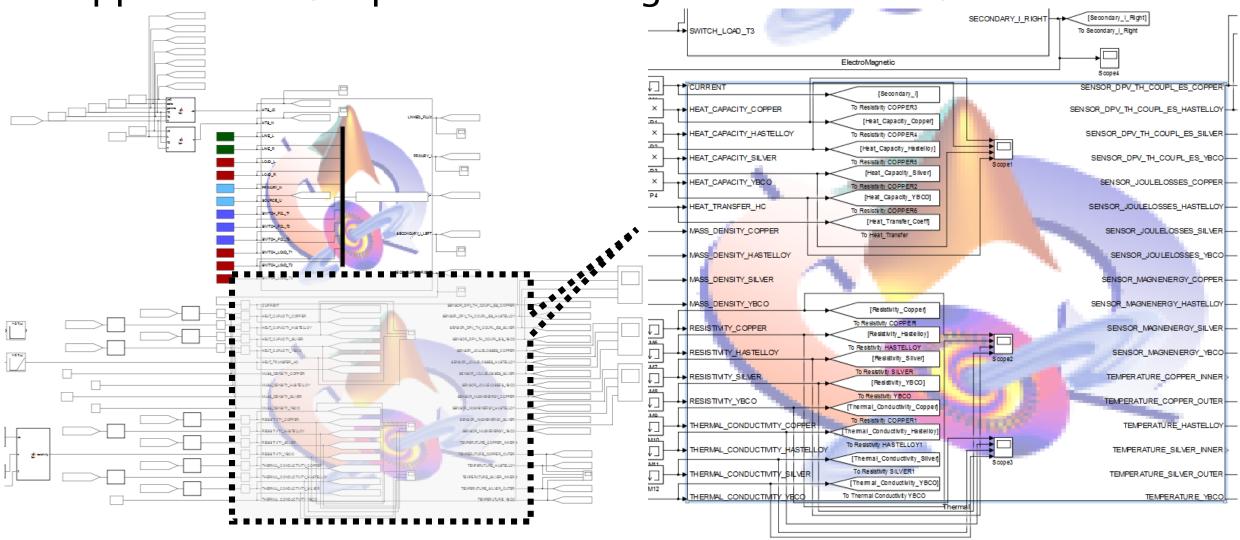
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### Approach 1: Coupled Electromagnetic-Thermal Simulation



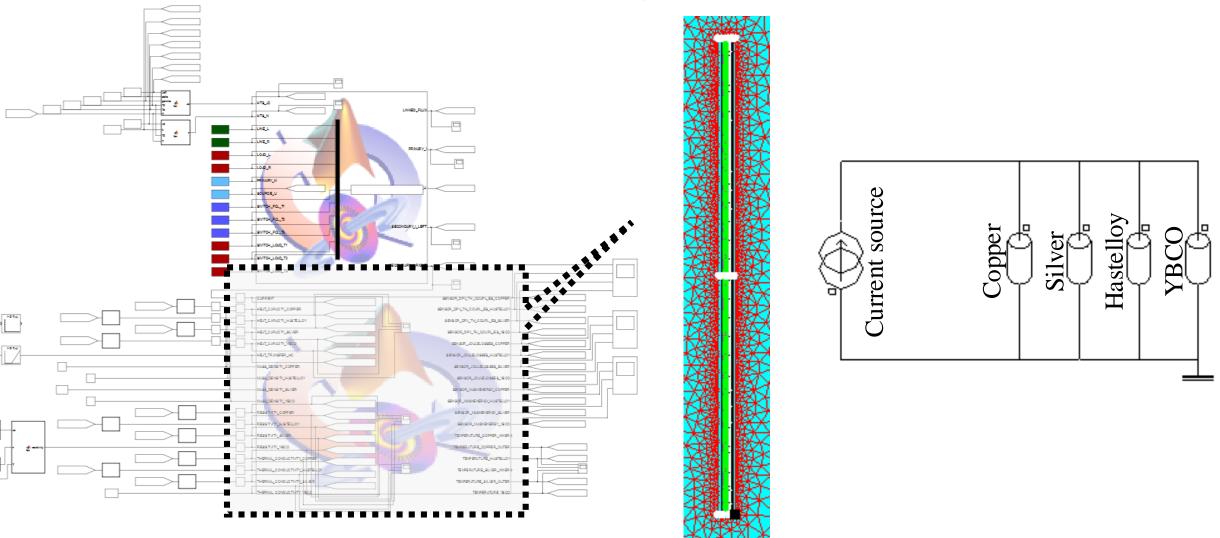
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Approach 1: Coupled Electromagnetic-Thermal Simulation



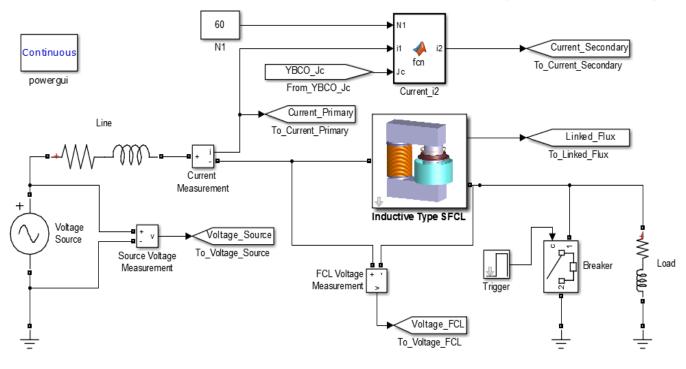
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### Approach 1: Coupled Electromagnetic-Thermal Simulation





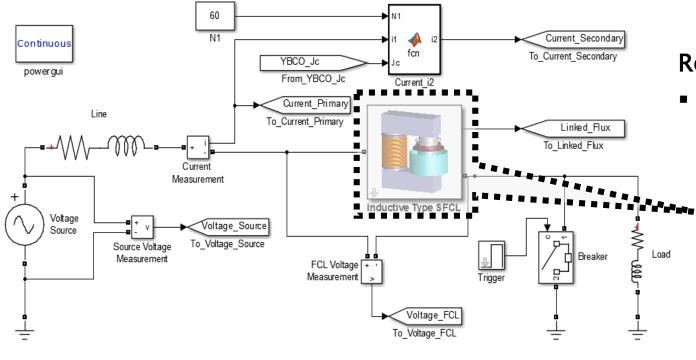
### Approach 2: Reverse Engineering Methodology



Matlab/Simulink

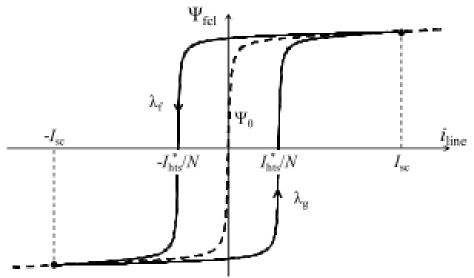
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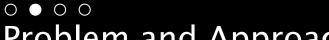
### Approach 2: Reverse Engineering Methodology



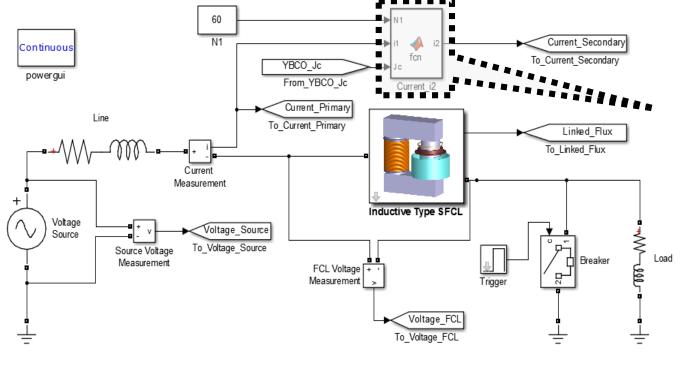
#### Reference:

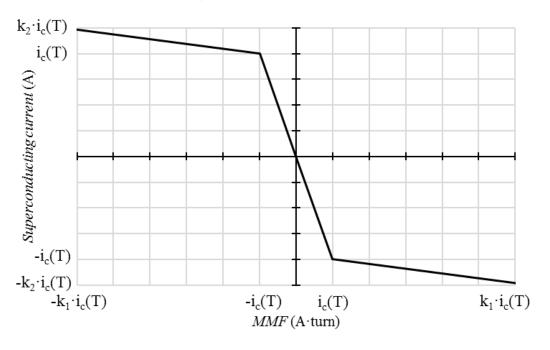
Pina J M, Suárez P, Neves M V, Álvarez A and Rodrigues A L 2010 Reverse engineering of inductive fault current limiters J. Phys. Conf. Ser. 234 032047.





### Approach 2: Reverse Engineering Methodology

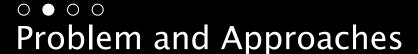




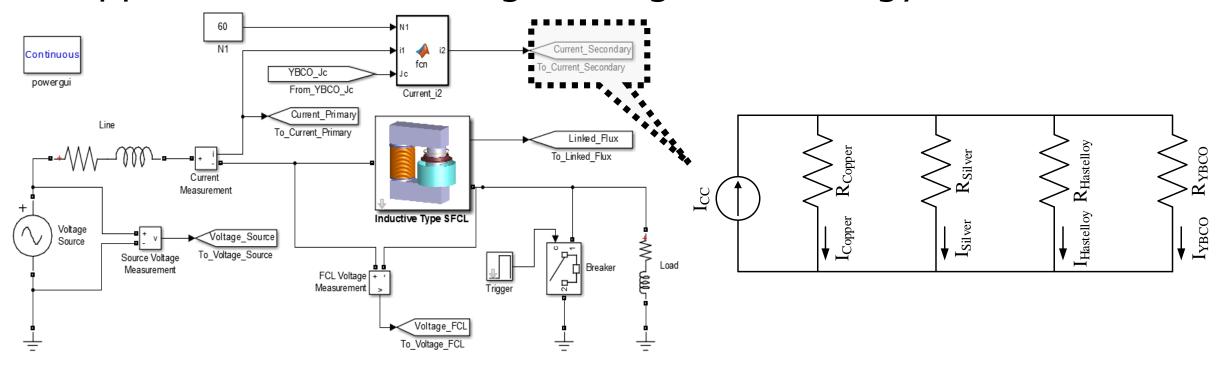
$$\begin{cases} i_2 = -N_1 \cdot i_1 & -i_c(T) \le N_1 \cdot i_1 \le i_c(T) \\ i_2 = \frac{1 - k_2}{k_1 - 1} \cdot (N_1 \cdot i_1) + \frac{k_1 - k_2}{k_1 - 1} \cdot (i_c(T)) & N_1 \cdot i_1 < -i_c(T) \\ i_2 = \frac{1 - k_2}{k_1 - 1} \cdot (N_1 \cdot i_1) + \frac{k_2 - k_1}{k_1 - 1} \cdot (i_c(T)) & N_1 \cdot i_1 > i_c(T) \end{cases}$$

$$i_C(T) = J_C(T) \cdot S_{Tape}$$

$$\begin{cases} k_1 = 90 \\ k_2 = 3 \end{cases}$$

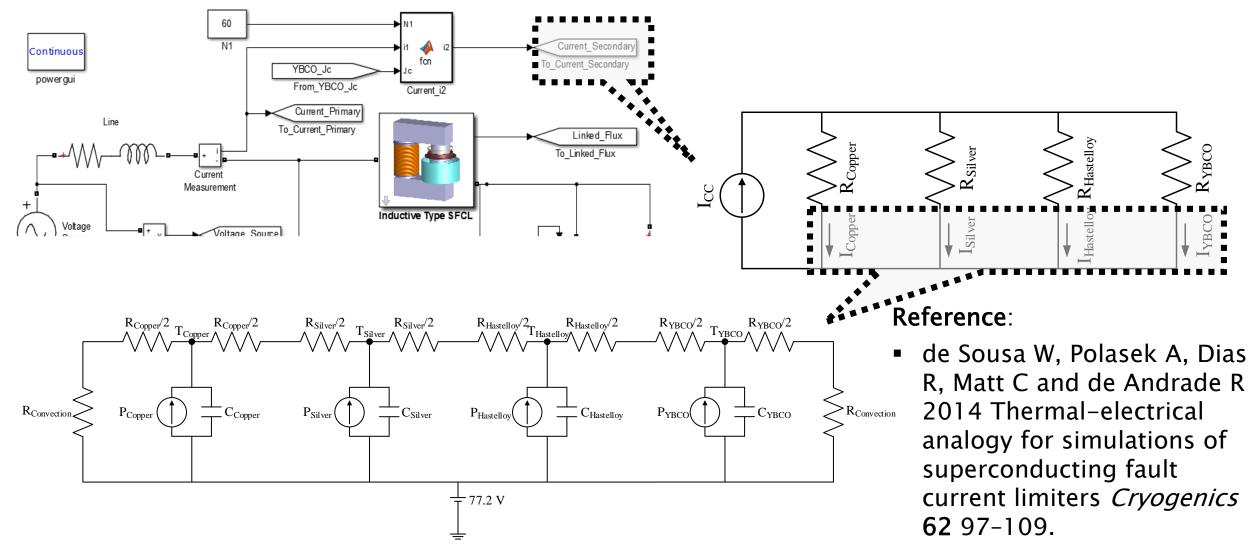


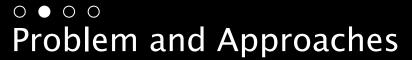
### Approach 2: Reverse Engineering Methodology



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### Approach 2: Reverse Engineering Methodology



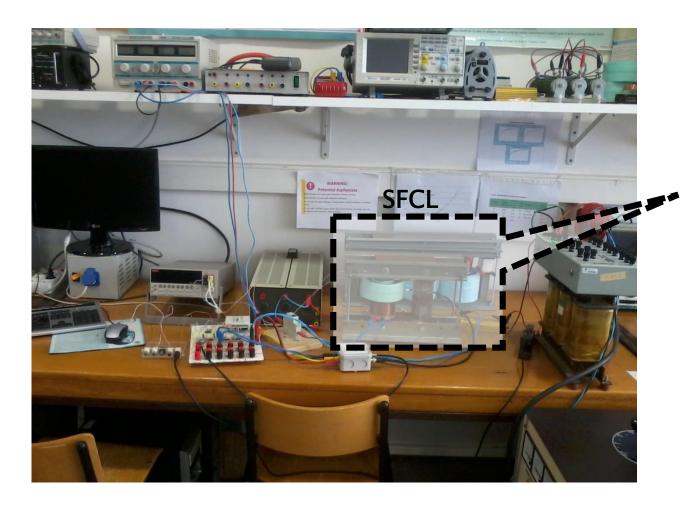


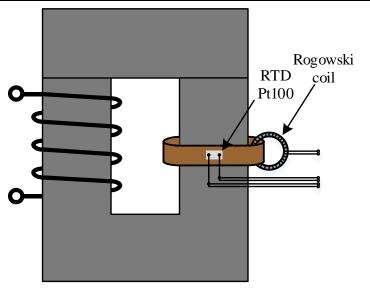
### Experimental Test Bench

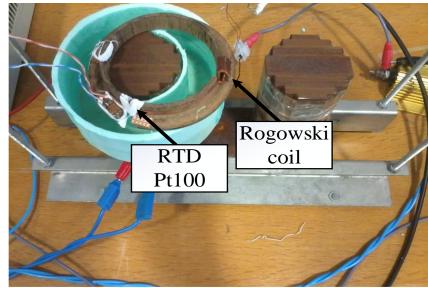


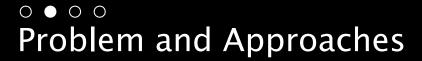


### Experimental Test Bench

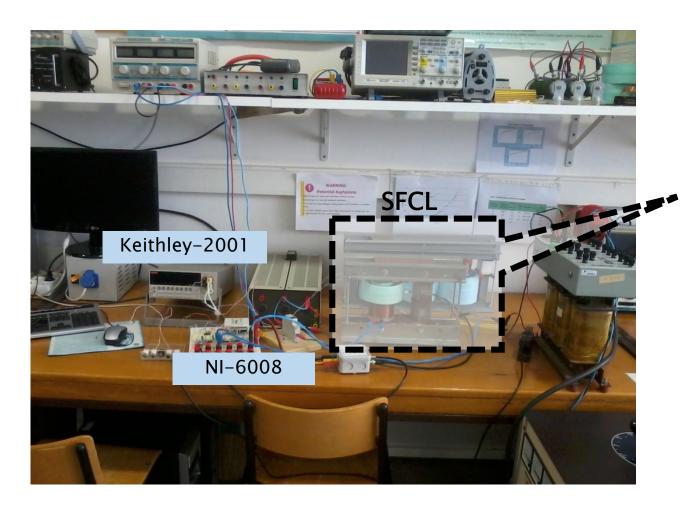


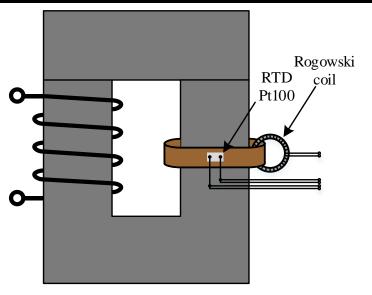


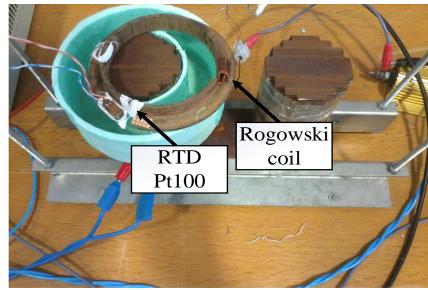




### Experimental Test Bench



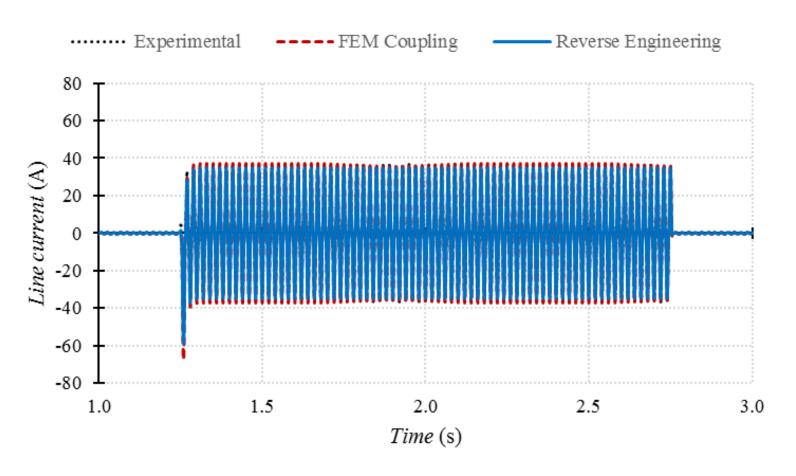




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### Results and Discussion

### Line Current



#### **Prospective current**:

■ 131.5 A

#### **Peak current:**

- 43.3 A (Experimental)
- 67.4 A (FEM Coupling)
- 59.0 A (Reverse Engineering)

### <u>Limited current (excluding 1st peak)</u>:

- 36.8 A (Experimental)
- 37.2 A (FEM Coupling)
- 34.9 A (Reverse Engineering)

#### $\circ \circ \bullet \circ$ Results and Discussion

1.5

2.0

Time (s)

Line current (A)

-80

1.0

#### Line Current 60 Line current (A) ····· Experimental ---- FEM Coupling 80 60 -60 -80 1.22 1.24 1.26 1.28 1.30 1.32 20 Time (s) - Reverse Engineering ····· Experimental -- FEM Coupling -20 60 -40 Line current (A) -60

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3.0

-60

2.68

2.70

2.72

2.74

Time (s)

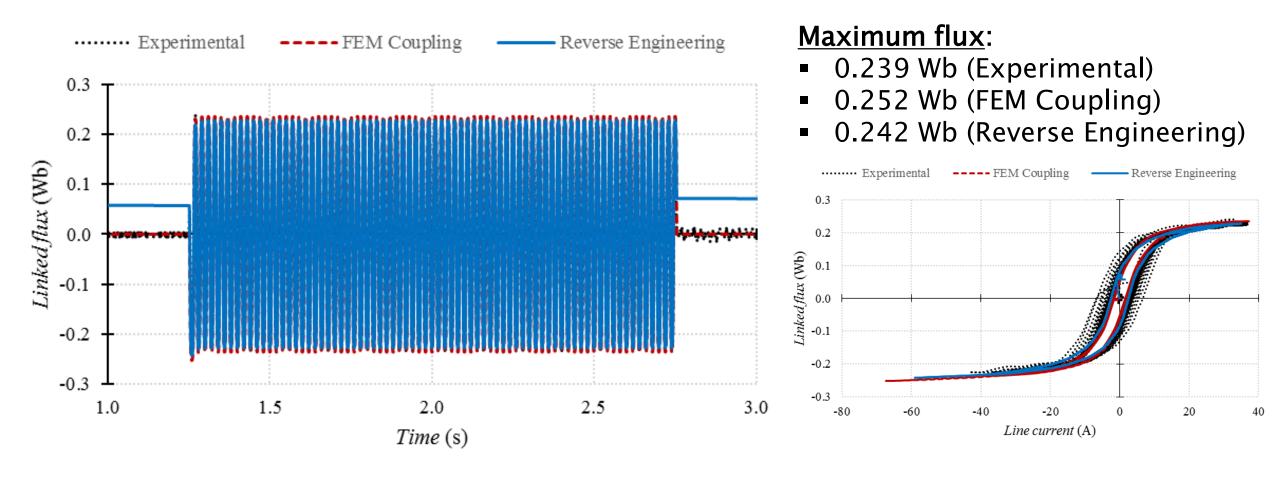
2.76

2.78

2.5

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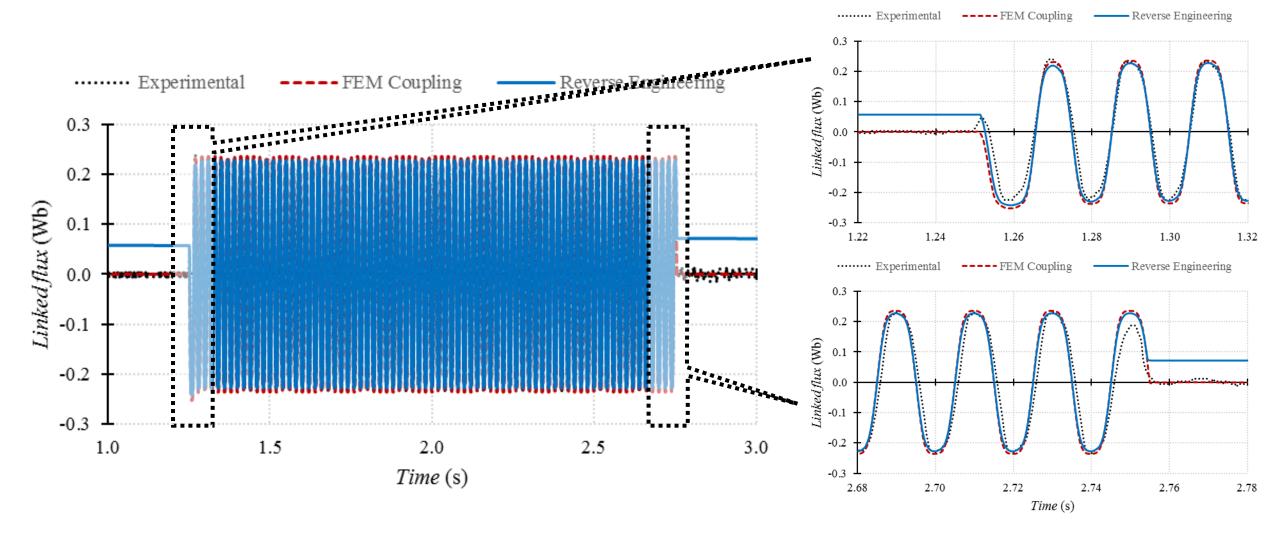
### Linked Flux and Hysteresis Loop



### Results and Discussion

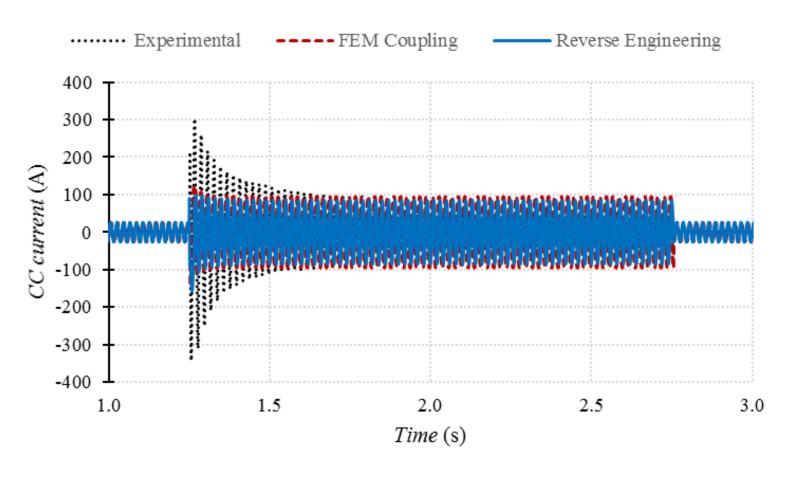
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### Linked Flux and Hysteresis Loop





### Current in Superconducting Secondary



#### Maximum current (1 st peak):

- 342.6 A (Experimental)
- 142.7 A (FEM Coupling)
- 152.0 A (Reverse Engineering)

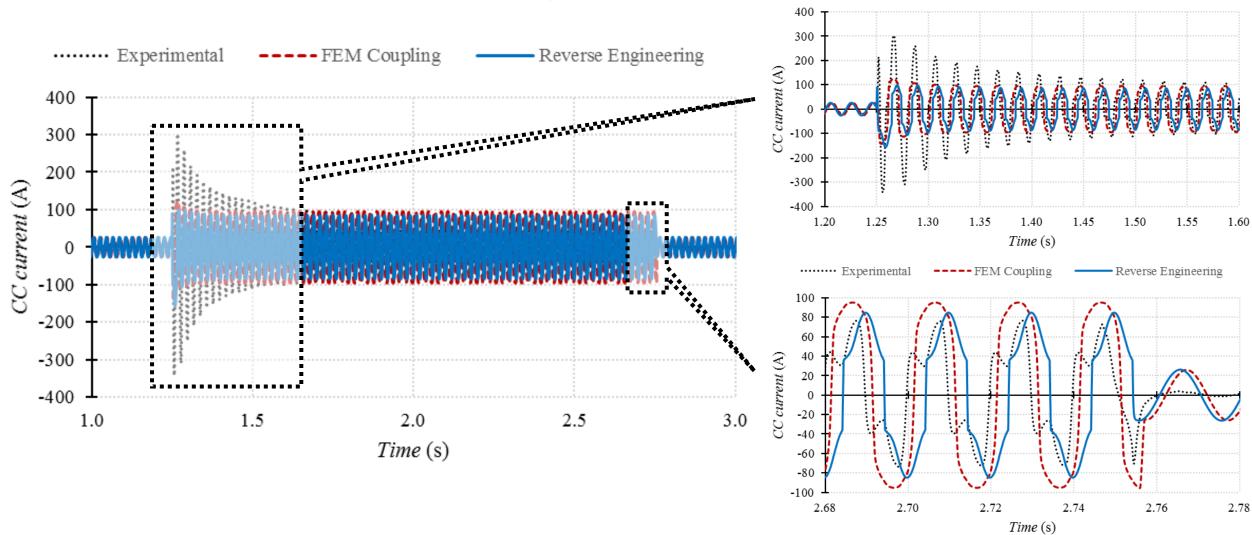
#### Maximum current (steady-state):

- 74.2 A (Experimental)
- 95.1 A (FEM Coupling)
- 82.9 A (Reverse Engineering)

### Results and Discussion

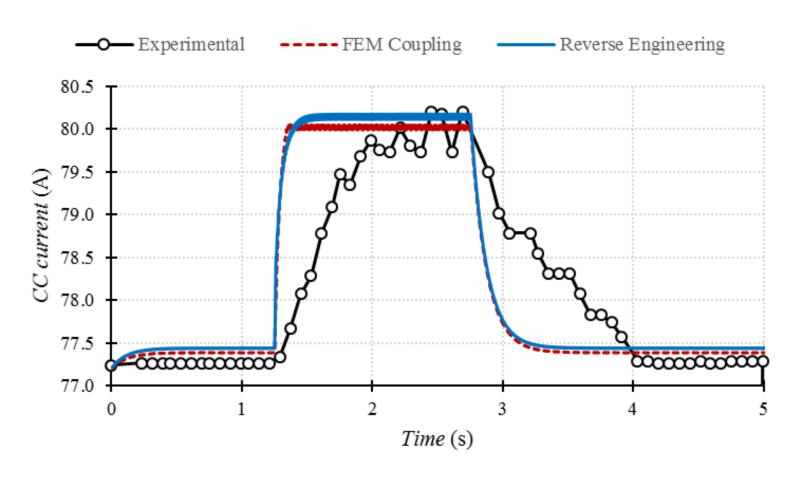
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Current in Superconducting Secondary



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### Temperature in Superconducting Secondary



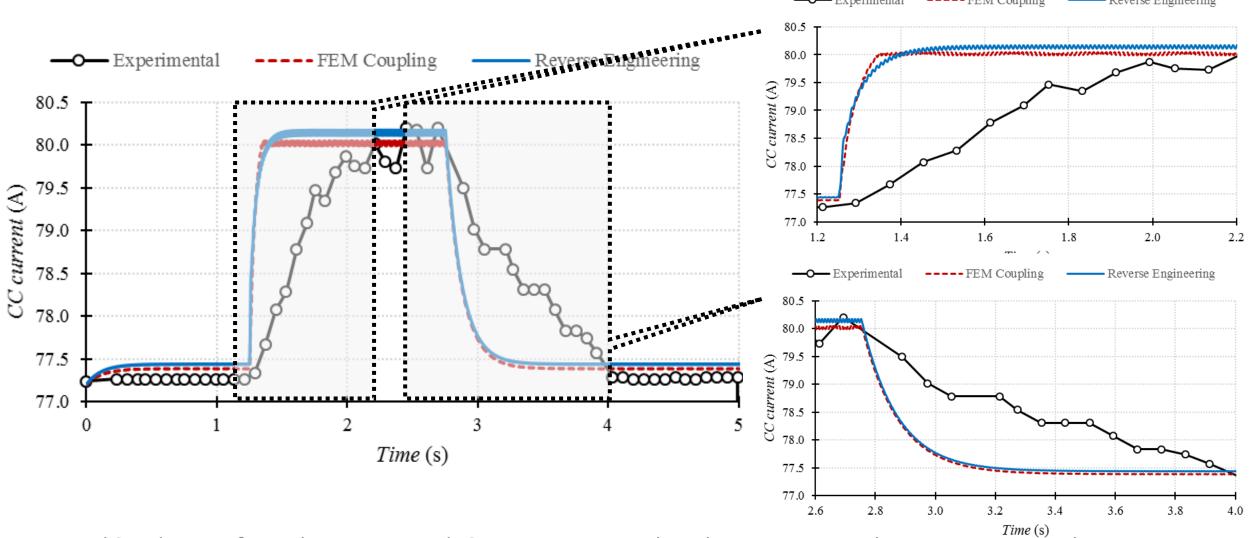
#### **Maximum temperature**:

- 80.2 K (Experimental)
- 80.1 K (FEM Coupling)
- 80.2 K (Reverse Engineering)

### Results and Discussion

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### Temperature in Superconducting Secondary



# Conclusions

### Conclusions

Good agreement between experimental and simulations were achieved.

The reverse engineering methodology provides results in **few seconds** while the electromagnetic-thermal coupled simulation based on FEM takes **several days** (5~7 days depending on mesh quality). Furthermore, complex grids can be easily simulated by means of the reverse engineering methodology.

Experimental temperature measurements shows drift due to thermal inertia of the RTD sensor. Ripple during fault occurrence is also observed.



Pedro Arsénio, PhD Student p.arsenio@campus.fct.unl.pt